Floating Bootstrap or Ground-Reference **D PACKAGE** (TOP VIEW) **High-Side Driver** Adaptive Dead-Time Control ENABLE [**□** воот 50-ns Max Rise/Fall Times With 3.3-nF Load □ NC IN \square 2 13 CROWBAR I 3 12 2.4-A Typical Output Current 4 11 NC 4.5-V to 15-V Supply Voltage Range SYNC I 5 10 □ LOWDR **TTL-Compatible Inputs** 6 9 □ NC $DT \square$ □ v_{cc} **Internal Schottky Bootstrap Diode** PGND □ **SYNC Control for Synchronous or Nonsynchronous Operation PWP PACKAGE** (TOP VIEW) **CROWBAR for OVP, Protects Against Faulted High-Side Power FETs** 10 ENABLE [Low Supply Current....3 mA Typical IN \square 2Γ 713 □ NC CROWBAR ___ 31 1₁₂ ☐ HIGHDR **Ideal for High-Current Single or Multiphase** 4 Thermal 11 NC □ BOOTLO **Power Supplies** Pad 5 SYNC I I_{10} LOWDR -40°C to 125°C Operating Virtual Junction 6 I 9 DT \square ☐ NC Temperature Range ¬¬ v_{cc} PGND Available in SOIC and TSSOP PowerPAD

description

Packages

The TPS2834 and TPS2835 are MOSFET drivers for synchronous-buck power stages. These devices are ideal for designing a high-performance power supply using switching controllers that do not include on-chip MOSFET drivers. The drivers are designed to deliver minimum 2-A peak currents into large capacitive loads. The high-side driver can be configured as ground-reference or as floating-bootstrap. An adaptive dead-time control circuit eliminates shoot-through currents through the main power FETs during switching transitions, and provides high efficiency for the buck regulator. The TPS2834 and TPS2835 have additional control functions: ENABLE, SYNC, and CROWBAR. Both high-side and low-side drivers are off when ENABLE is low. The driver is configured as a nonsynchronous-buck driver disabling the low-side driver when SYNC is low. The CROWBAR function turns on the low-side power FET, overriding the IN signal, for overvoltage protection against faulted high-side power FETs.

NC - No internal connection

The TPS2834 has a noninverting input, while the TPS2835 has an inverting input. These drivers are available in 14-terminal SOIC and thermally enhanced TSSOP PowerPADTM packages and operate over a junction temperature range of -40° C to 125° C.

Related Synchronous MOSFET Drivers

DEVICE NAME	ADDITIONAL FEATURES	INPUTS		
TPS2830			Noninverted	
TPS2831	ENABLE, SYNC, and CROWBAR	CMOS	Inverted	
TPS2832	WO ENABLE OVALO LODOWBAR	01100	Noninverted	
TPS2833	W/O ENABLE, SYNC, and CROWBAR	CMOS	Inverted	
TPS2836			Noninverted	
TPS2837	W/O ENABLE, SYNC, and CROWBAR	TTL	Inverted	



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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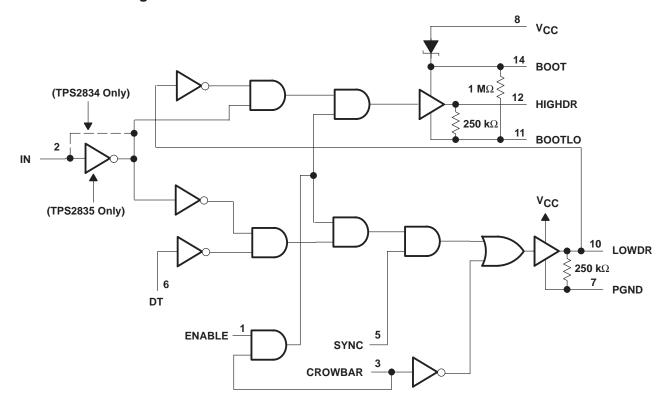


AVAILABLE OPTIONS

	PACKAGED DEVICES			
TJ	SOIC (D)	TSSOP (PWP)		
– 40°C to 125°C	TPS2834D TPS2835D	TPS2834PWP TPS2835PWP		

The D and PWP packages are available taped and reeled. Add R suffix to device type (e.g., TPS2834DR)

functional block diagram





Terminal Functions

TERMI	TERMINAL		DECORPTION			
NAME NO.		1/0	DESCRIPTION			
воот	14	I	Bootstrap terminal. A ceramic capacitor is connected between BOOT and BOOTLO to develop the floating bootstrap voltage for the high-side MOSFET. The capacitor value is typically between 0.1 μ F and 1 μ F.			
BOOTLO	11	0	This terminal connects to the junction of the high-side and low-side MOSFETs.			
CROWBAR 3		I	CROWBAR can to be driven by an external OVP circuit to protect against a short across the high-side MOSFET. If CROWBAR is driven low, the low-side driver will be turned on and the high-side driver will be turned off, independent of the status of all other control terminals.			
DT	6	I	Dead-time control terminal. Connect DT to the junction of the high-side and low-side MOSFETs.			
ENABLE	1	I	If ENABLE is low, both drivers are off.			
HIGHDR	12	0	Output drive for the high-side power MOSFET			
IN	2	I	Input signal to the MOSFET drivers (noninverting input for the TPS2834; inverting input for the TPS2835).			
LOWDR	10	0	Output drive for the low-side power MOSFET			
NC	4, 9, 13		No internal connection			
PGND	7		Power ground. Connect to the FET power ground.			
SYNC	5	I	Synchronous rectifier enable terminal. If SYNC is low, the low-side driver is always off; If SYNC is high, the low-side driver provides gate drive to the low-side MOSFET.			
VCC	8	I	Input supply. Recommended that a 1-μF capacitor be connected from V _{CC} to PGND.			

detailed description

low-side driver

The low-side driver is designed to drive low r_{DS(on)} N-channel MOSFETs. The current rating of the driver is 2 A, source and sink.

high-side driver

The high-side driver is designed to drive low r_{DS(on)} N-channel MOSFETs. The current rating of the driver is 2 A, source and sink. The high-side driver can be configured as a GND-reference driver or as a floating bootstrap driver. The internal bootstrap diode is a Schottky, for improved drive efficiency. The maximum voltage that can be applied from BOOT to ground is 30 V.

dead-time (DT) control

Dead-time control prevents shoot-through current from flowing through the main power FETs during switching transitions by controlling the turnon times of the MOSFET drivers. The high-side driver is not allowed to turn on until the gate drive voltage to the low-side FET is low, and the low-side driver is not allowed to turn on until the voltage at the junction of the power FETs (Vdrain) is low; the TTL-compatible DT terminal connects to the junction of the power FETs.

ENABLE

The ENABLE terminal enables the drivers. When enable is low, the output drivers are low. ENABLE is a TTL-compatible digital terminal.

IN

The IN terminal is a TTL-compatible digital terminal that is the input control signal for the drivers. The TPS2834 has a noninverting input; the TPS2835 has an inverting input.



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detailed description (continued)

SYNC

The SYNC terminal controls whether the drivers operate in synchronous or nonsynchronous mode. In synchronous mode, the low-side FET is operated as a synchronous rectifier. In nonsynchronous mode, the low-side FET is always off. SYNC is a TTL-compatible digital terminal.

CROWBAR

The CROWBAR terminal overrides the normal operation of the driver. When CROWBAR is low, the low-side FET turns on to act as a clamp, protecting the output voltage of the dc/dc converter against overvoltages due to a short across the high-side FET. VIN should be fused to protect the low-side FET. CROWBAR is a TTL-compatible digital terminal.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Supply voltage range, V _{CC} (see Note 1)	–0.3 V to 16 V
Input voltage range: BOOT to PGND (high-side driver ON)	–0.3 V to 30 V
BOOTLO to PGND	–0.3 V to 16 V
BOOT to BOOTLO	–0.3 V to 16 V
ENABLE, SYNC, and CROWBAR	–0.3 V to 16 V
IN	–0.3 V to 16 V
DT	–0.3 V to 30 V
Continuous total power dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, T _J	–40°C to 125°C
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Unless otherwise specified, all voltages are with respect to PGND.

DISSIPATION RATING TABLE

PACKAGE	$T_{\hbox{\scriptsize A}} \leq 25^{\circ}\hbox{\scriptsize C}$	DERATING FACTOR	T _A = 70°C	T _A = 85°C
PWP with solder [‡]	2668	26.68 mW/°C	1467	1067
PWP without solder [‡]	1024	10.24 mW/°C	563	409
D	749	7.49 mW/°C	412	300

JUNCTION-CASE THERMAL RESISTANCE TABLE

PWP Junction-case thermal resistance	2.07 °C/W
--------------------------------------	-----------

[‡] Test Board Conditions:

- 1. Thickness: 0.062"
- 2. $3'' \times 3''$ (for packages <27 mm long)
- 3. $4'' \times 4''$ (for packages >27 mm long)
- 4. 2-oz copper traces located on the top of the board (0.071 mm thick)
- 5. Copper areas located on the top and bottom of the PCB for soldering
- 6. Power and ground planes, 1-oz copper (0.036 mm thick)
- 7. Thermal vias, 0.33 mm diameter, 1.5 mm pitch
- 8. Thermal isolation of power plane

For more information, refer to TI technical brief literature number SLMA002.



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recommended operating conditions

		MIN	NOM MA	UNIT
Supply voltage,	Vcc	4.5	1	5 V
Input voltage	BOOT to PGND	4.5	2	8 V

electrical characteristics over recommended operating virtual junction temperature range, V_{CC} = 6.5 V, ENABLE = High, C_L = 3.3 nF (unless otherwise noted)

supply current

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VCC	Supply voltage range		4.5		15	V
		V(ENABLE) = LOW, V _{CC} =15 V			100	
		V _(ENABLE) = HIGH, V _{CC} =15 V		300	400	μΑ
VCC	Quiescent current			3		mA

NOTE 2: Ensured by design, not production tested.

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electrical characteristics over recommended operating virtual junction temperature range, $V_{CC} = 6.5 \text{ V}$, ENABLE = High, $C_L = 3.3 \text{ nF}$ (unless otherwise noted) (continued)

output drivers

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
			V(BOOT) - V(BOOTLO) = 4.5 V, V(HIGHDR) = 4 V	0.7	1.1			
Peak output current Output resistance	High-side sink (see Note 3)	Duty cycle < 2%, t _{pw} < 100 μs (see Note 2)	V(BOOT) - V(BOOTLO) = 6.5 V, V(HIGHDR) = 5 V	1.1	1.5		Α	
		(666 116.6 2)	V(BOOT) - V(BOOTLO) = 12 V, V(HIGHDR) = 10.5 V	2	2.4			
			V(BOOT) - V(BOOTLO) = 4.5 V, V(HIGHDR) = 0.5V	1.2	1.4			
	High-side source (see Note 3)	Duty cycle < 2%, t _{pw} < 100 μs (see Note 2)	V(BOOT) - V(BOOTLO) = 6.5 V, V(HIGHDR) = 1.5 V	1.3	1.6		А	
		(000 11010 2)	V(BOOT) - V(BOOTLO) = 12 V, V(HIGHDR) = 1.5 V	2.3	2.7			
		Duty cycle < 2%,	V _{CC} = 4.5 V, V _(LOWDR) = 4 V	1.3	1.8			
	Low-side sink (see Note 3)	t _{pw} < 100 μs	$V_{CC} = 6.5 \text{ V}, V_{(LOWDR)} = 5 \text{ V}$	2	2.5		A	
		(see Note 2)	$V_{CC} = 12 \text{ V}, V_{(LOWDR)} = 10.5 \text{ V}$	3	3.5			
	Low-side source (see Note 3)	Duty cycle < 2%,	$V_{CC} = 4.5 \text{ V}, V_{LOWDR}) = 0.5 \text{V}$	1.4	1.7			
		t _{pw} < 100 μs (see Note 2)	$V_{CC} = 6.5 \text{ V}, V_{(LOWDR)} = 1.5 \text{ V}$	2	2.4			
			V _{CC} = 12 V, V _(LOWDR0) = 1.5 V	2.5	3			
			V(BOOT) - V(BOOTLO) = 4.5 V, V(HIGHDR)= 0.5 V			5		
	High-side sink (see Note 3)		V(BOOT) - V(BOOTLO) = 6.5 V, V(HIGHDR) = 0.5 V			5	Ω	
			V(BOOT) - V(BOOTLO) = 12 V, V(HIGHDR) = 0.5 V			5		
			V(BOOT) - V(BOOTLO) = 4.5 V, V(HIGHDR) = 4 V			75		
	High-side source (see Note 3	s)	V(BOOT) - V(BOOTLO) = 6.5 V, V(HIGHDR)= 6 V			75	Ω	
. 55/5/4/100			V(BOOT) - V(BOOTLO) = 12 V, V(HIGHDR) =11.5 V			75		
			V(DRV) = 4.5 V, V(LOWDR) = 0.5 V			9		
	Low-side sink (see Note 3)		V(DRV) = 6.5 V, V(LOWDR) = 0.5 V			7.5	Ω	
			$V_{(DRV)} = 12 \text{ V}, V_{(LOWDR)} = 0.5 \text{ V}$			6	<u> </u>	
			V(DRV) = 4.5 V, V(LOWDR) = 4 V			75		
	Low-side source (see Note 3))	V _(DRV) = 6.5 V, V _(LOWDR) = 6 V			75	Ω	
			$V_{(DRV)} = 12 \text{ V}, V_{(LOWDR)} = 11.5 \text{ V}$			75		

NOTES: 2: Ensured by design, not production tested.

3. The pullup/pulldown circuits of the drivers are bipolar and MOSFET transistors in parallel. The peak output current rating is the combined current from the bipolar and MOSFET transistors. The output resistance is the r_{DS(on)} of the MOSFET transistor when the voltage on the driver output is less than the saturation voltage of the bipolar transistor.



electrical characteristics over recommended operating virtual junction temperature range, $V_{CC} = 6.5 \text{ V}$, ENABLE = High, $C_L = 3.3 \text{ nF}$ (unless otherwise noted) (continued)

dead-time control

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
٧ıH	High-level input voltage	LOWIDD	Occasilla V Carana (ana Mata 2)	0.7V _{CC}			
VIL	Low-level input voltage	LOWDR	Over the V _{CC} range (see Note 2)			1	V
V_{IH}	High-level input voltage	DT	Over the V renge	2			V
VIL	Low-level input voltage	וטו	Over the V _{CC} range			1	V

NOTE 2: Ensured by design, not production tested.

digital control terminals (IN, CROWBAR, SYNC, ENABLE)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIH	High-level input voltage	O conthact /	2			V
VIL	Low-level input voltage	Over the V _{CC} range			1	V

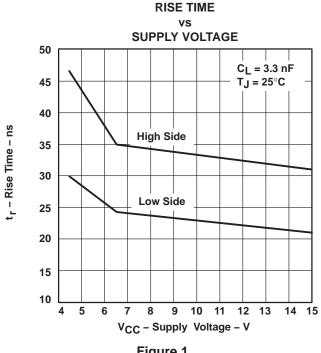
switching characteristics over recommended operating virtual junction temperature range, ENABLE = High, C_L = 3.3 nF (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT	
		V(BOOT) = 4.5 V, V(BOOTLO) = 0 V		60		
	HIGHDR output (see Note 2)	$V_{(BOOT)} = 6.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		50	ns	
Rise time		$V_{(BOOT)} = 12 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		50		
Rise time		V _{CC} = 4.5 V		40		
	LOWDR output (see Note 2)	V _{CC} = 6.5 V		30	ns	
		V _{CC} = 12 V		30		
		$V_{(BOOT)} = 4.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		50		
	HIGHDR output (see Note 2)	$V_{(BOOT)} = 6.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		40	ns	
Fall time		$V_{(BOOT)} = 12 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		40		
raii tiirie	LOWDR output (see Note 2)	V _{CC} = 4.5 V		40	ns	
		V _{CC} = 6.5 V		30		
		V _{CC} = 12 V		30		
	HIGHDR going low (excluding dead time) (see Note 2)	$V_{(BOOT)} = 4.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		95	ns	
		$V_{(BOOT)} = 6.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		80		
Dranagation delay time		$V_{(BOOT)} = 12 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		70		
Propagation delay time	LOWDR going high (excluding	$V_{(BOOT)} = 4.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		80		
	dead time) (see Note 2)	$V_{(BOOT)} = 6.5 \text{ V}, V_{(BOOTLO)} = 0 \text{ V}$		70	ns	
		V(BOOT) = 12 V, V(BOOTLO) = 0 V		60		
		V _{CC} = 4.5 V		80		
Propagation delay time	LOWDR going low (excluding dead time) (see Note 2)	V _{CC} = 6.5 V		70	ns	
	4044 tillioj (300 140to 2)	V _{CC} = 12 V		60		
	DT	V _{CC} = 4.5 V	40	170		
Driver nonoverlap time	DT to LOWDR and LOWDR to HIGHDR (see Note 2)	V _{CC} = 6.5 V	25	135	ns	
niver nonovenap time	1.10.151((000 14010 2)	V _{CC} = 12 V	15	85		

NOTE 2: Ensured by design, not production tested.



TYPICAL CHARACTERISTICS



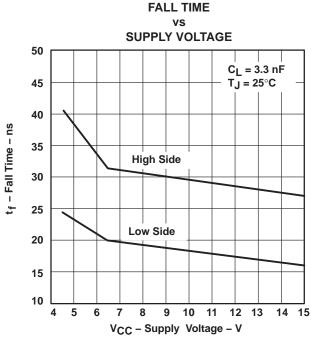
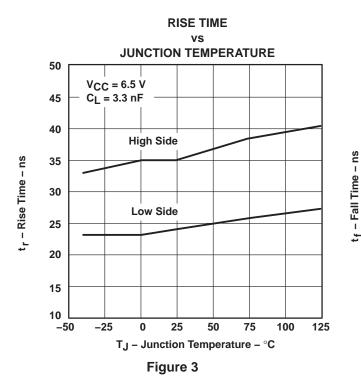


Figure 1

Figure 2



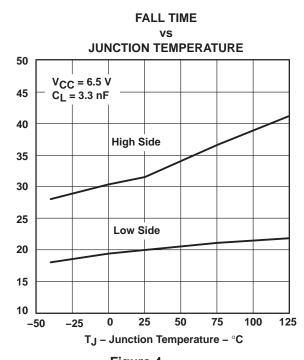
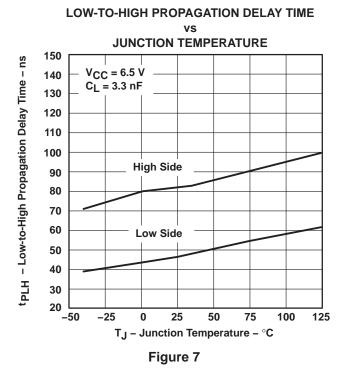


Figure 4

TYPICAL CHARACTERISTICS

LOW-TO-HIGH PROPAGATION DELAY TIME SUPPLY VOLTAGE, LOW TO HIGH LEVEL 150 tpLH - Low-to-High Propagation Delay Time - ns C_L = 3.3 nF 140 T_J = 25°C 130 120 110 100 90 80 70 60 Low Side 50 40 30 20 5 6 9 10 11 V_{CC} - Supply Voltage - V Figure 5

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HIGH-TO-LOW PROPAGATION DELAY TIME vs SUPPLY VOLTAGE, HIGH TO LOW LEVEL

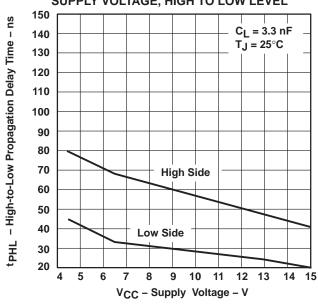


Figure 6

HIGH-TO-LOW PROPAGATION DELAY TIME

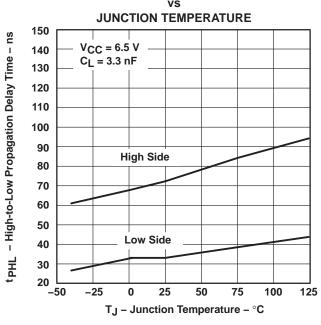


Figure 8

TYPICAL CHARACTERISTICS

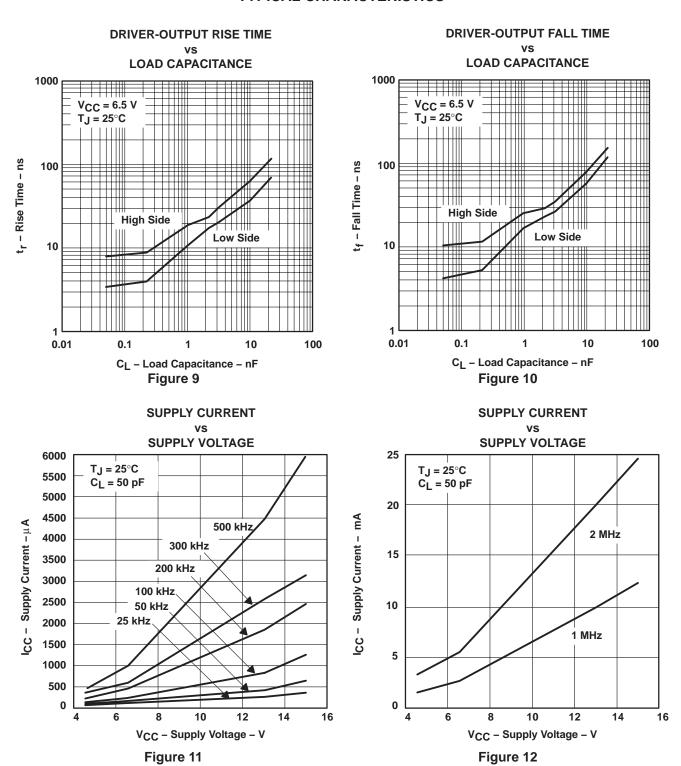




Figure 16

TYPICAL CHARACTERISTICS

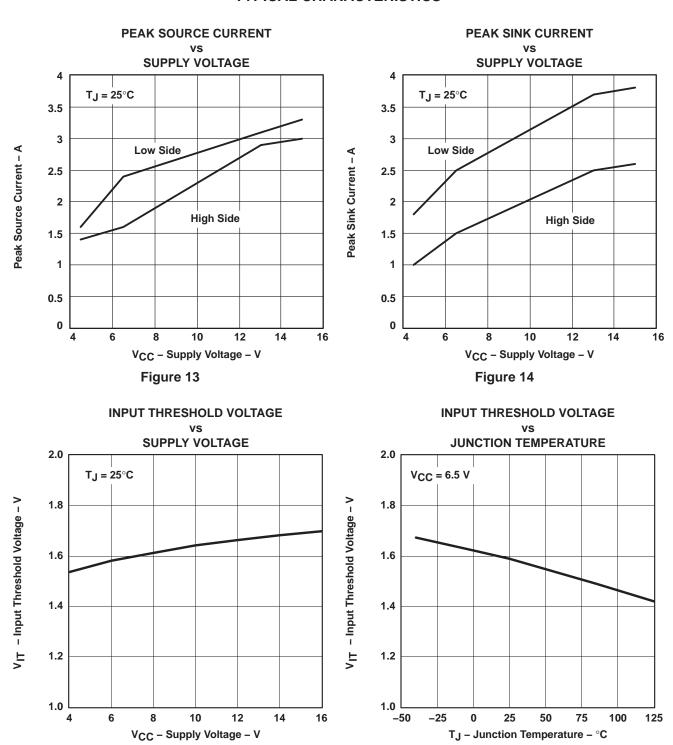


Figure 15

APPLICATION INFORMATION

Figure 17 shows the circuit schematic of a 100-kHz synchronous-buck converter implemented with a TL5001A pulse-width-modulation (PWM) controller and a TPS2835 driver. The converter operates over an input range from 4.5 V to 12 V and has a 3.3-V output. The circuit can supply 3 A continuous load. The converter achieves an efficiency of 94% for $V_{IN} = 5$ V, $I_{load} = 1$ A, and 93% for $V_{IN} = 5$ V, $I_{load} = 3$ A.

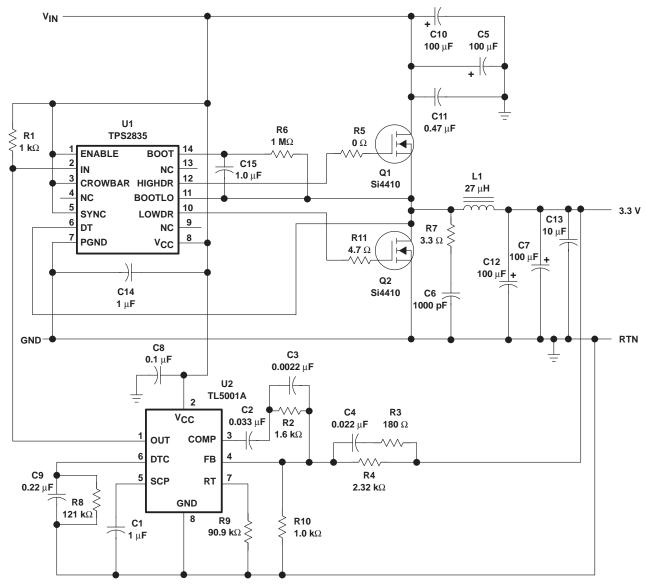


Figure 17. 3.3-V 3-A Synchronous-Buck Converter Circuit



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APPLICATION INFORMATION

Great care should be taken when laying out the PC board. The power-processing section is the most critical and will generate large amounts of EMI if not properly configured. The junction of Q1, Q2, and L1 should be very tight. The connection from Q1 drain to the positive sides of C5, C10, and C11 and the connection from Q2 source to the negative sides of C5, C10, and C11 should be as short as possible. The negative terminals of C7 and C12 should also be connected to Q2 source.

Next, the traces from the MOSFET driver to the power switches should be considered. The BOOTLO signal from the junction of Q1 and Q2 carries the large gate drive current pulses and should be as heavy as the gate drive traces. The bypass capacitor (C14) should be tied directly across V_{CC} and PGND.

The next most sensitive node is the FB node on the controller (terminal 4 on the TL5001A). This node is very sensitive to noise pickup and should be isolated from the high-current power stage and be as short as possible. The ground around the controller and low-level circuitry should be tied to the power ground as the output. If these three areas are properly laid out, the rest of the circuit should not have other EMI problems and the power supply will be relatively free of noise.







10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2834D	ACTIVE	SOIC	D	14	50	RoHS & Green	(6) NIPDAU	Level-1-260C-UNLIM	-40 to 125	2834	Samples
TPS2834DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2834	Samples
TPS2834PWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS2834	Samples
TPS2834PWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS2834	Samples
TPS2835D	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2835	Samples
TPS2835PWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS2835	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

10-Dec-2020

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

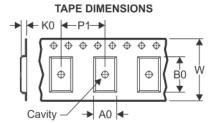
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

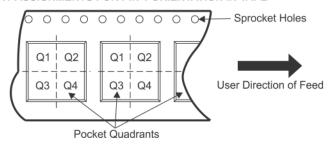
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

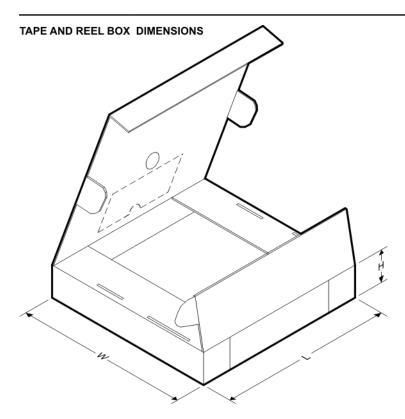
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2834PWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2834PWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

7 till difficilities die fremman								
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TPS2834D	D	SOIC	14	50	505.46	6.76	3810	4
TPS2834PWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5
TPS2835D	D	SOIC	14	50	505.46	6.76	3810	4
TPS2835PWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

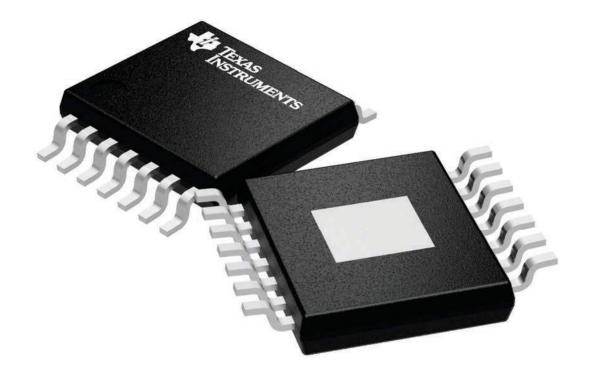
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



4.4 x 5.0, 0.65 mm pitch

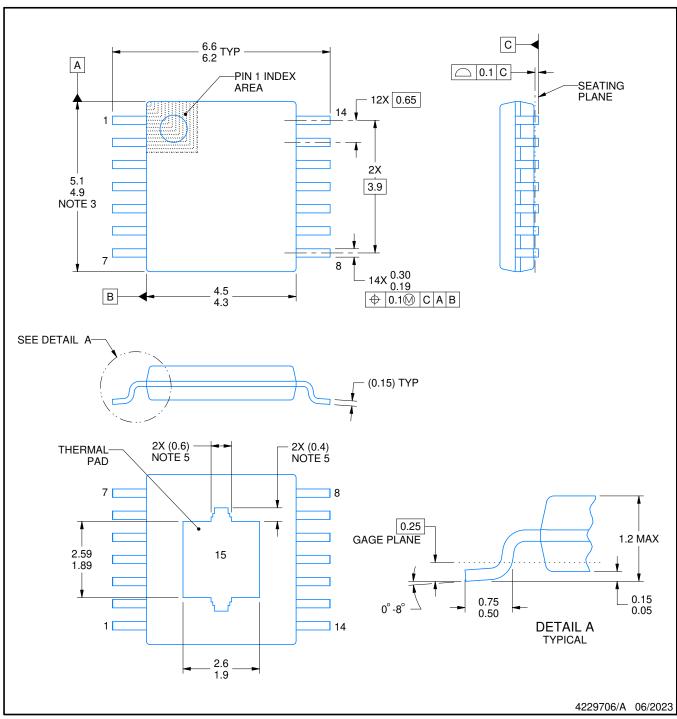
PLASTIC SMALL OUTLINE

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



PowerPAD[™] TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

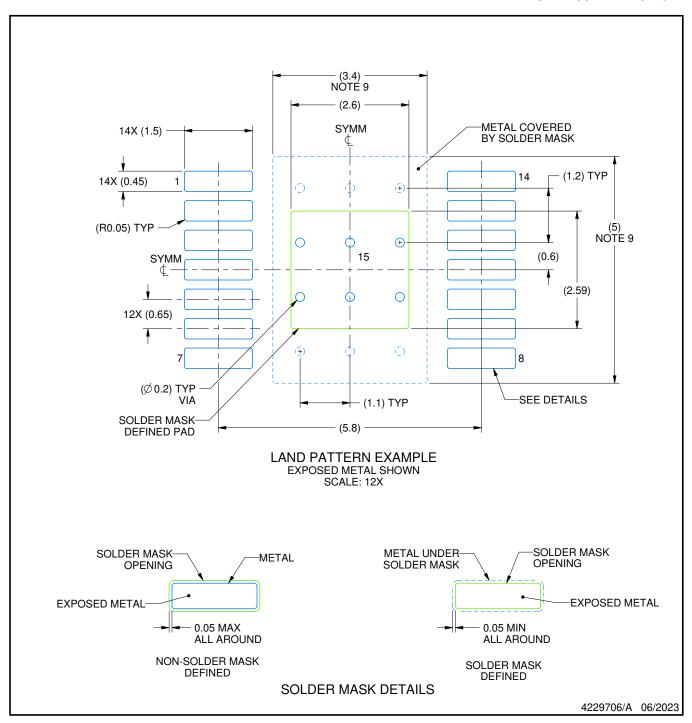
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.
- 5. Features may differ or may not be present.



SMALL OUTLINE PACKAGE

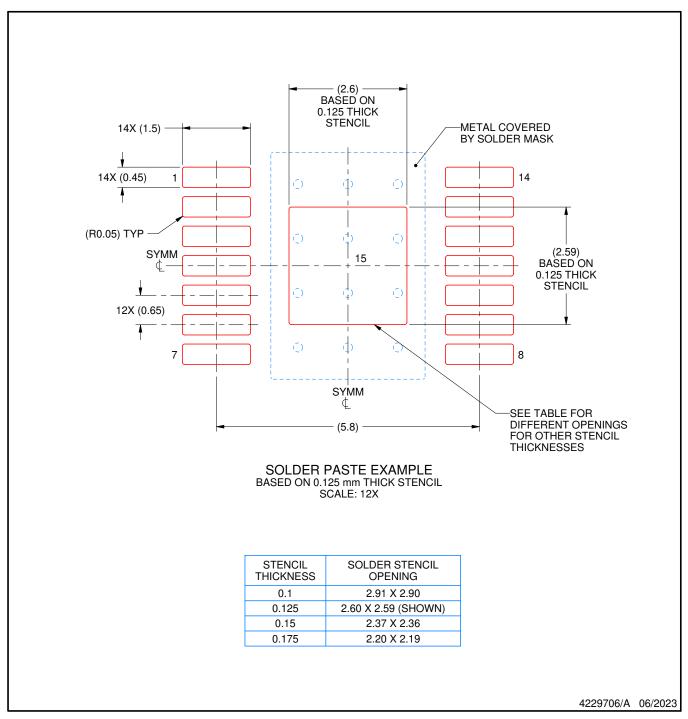


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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